

Absorption of surface acoustic-waves by quantum dots: discrete spectrum limit

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(received ; accepted in final form)

PACS. 72.50.+b – Acoustoelectric effects.

PACS. 73.20.Fz – Weak localization effects.

Abstract. – The absorption of surface acoustic waves (SAW's) by an array of quantum dots in which the mean level spacing Δ is larger than the sound frequency ω , the temperature T , and the phase breaking rate τ_ϕ^{-1} is considered. The direct and the intra-level (Debye) contributions to the SAW attenuation coefficient Γ are evaluated, and it is shown that the sensitivity to weak magnetic fields and spin-orbit scattering (“weak localization effects”) is dramatically enhanced as compared to the case of a continuous spectrum, $\Delta < \tau_\phi^{-1}$. It is argued that the non-invasive measurement of Γ represents a new tool for the investigation of the temperature dependence of the energy relaxation rate, τ_e^{-1} , and the phase breaking rate, τ_ϕ^{-1} , of isolated electronic systems.

Very recently, surface acoustic waves (SAW's) have been used to study mesoscopic systems [1, 2, 3]. In ref. [1], the direct acousto-electric current induced by a SAW through a single quantum point contact, which can be considered as a quasi-one-dimensional channel of length $0.5 \mu\text{m}$, has been observed. In refs. [2] and [3], the SAW attenuation and the change of the sound velocity due to arrays of quantum wires and quantum dots patterned in a two-dimensional electron gas (2DEG) have been measured as a function of a quantizing magnetic field. The experiments reported in ref. [3] include dots with a lithographic size as small as 250 nm , their electronic size being probably much smaller. The measurements of refs. [2] and [3] were done on isolated dots and wires, *i.e.*, no current-carrying contacts were attached to the mesoscopic systems. This preserves the phase coherence of the electronic wave functions and eliminates Coulomb blockade effects. Thus, the SAW method provides a novel tool for non-invasive investigations of nanostructures. Experimental studies of isolated mesoscopic systems may also use the polarizability of, or the microwave absorption due to small metal particles, as recently discussed in refs. [4, 5] and [6], respectively.

In this Letter we calculate the attenuation coefficient, Γ , of SAW's due to an array of quantum dots. We consider dots with an electronic size in the nanometer range, *e.g.* $L = 300$ nm, which corresponds to the mean level spacing $\Delta \sim 1$ K. Then, at low enough temperatures, the phase breaking rate $\tau_\phi^{-1} \ll \Delta$, *i.e.*, the energy levels are only slightly broadened due to inelastic processes. Since typical SAW frequencies are in the range $\omega \sim 10^8 \div 10^9$ s⁻¹ = $1 \div 10$ mK $\ll \Delta$, the discreteness of the spectrum is relevant, requiring the consideration of both direct and relaxational absorption processes, to be explained below. We present the dependence of Γ on the frequency ω , the size L of the dots and the temperature T , showing that the relaxational absorption is dominant in a wide range of parameters. Γ also exhibits weak localization effects, *i.e.*, it is sensitive to weak magnetic fields B and the spin-orbit scattering rate τ_{so}^{-1} . This sensitivity is dramatically enhanced as compared to a quasicontinuous spectrum ($\tau_\phi^{-1} > \Delta$ or $\omega \gg \Delta$), because the sound absorption resolves level correlation effects appearing on a very small energy scale, $\epsilon < \Delta$. Direct and relaxational processes involve different time scales of the electronic system, namely the phase coherence time τ_ϕ and the energy relaxation time τ_ϵ , suggesting that SAW attenuation measurements may provide information on their temperature dependence and magnitude in *isolated* mesoscopic systems. This could contribute to the clarification of the controversial issue related to the significant discrepancies [7, 8, 9] between the theoretical predictions for these times and recent experimental results obtained from *transport* measurements. This applies to both the electron-electron interaction and the interaction between electrons and thermal phonons; we comment below on the relevance of these two interactions for the present considerations.

At sufficiently low temperatures, when the inelastic level broadening and the thermal broadening of the distribution function are significantly smaller than Δ , the sound absorption depends strongly on the existence of narrow pairs of levels whose separations are $\ll \Delta$. In general, two absorption mechanisms can be identified [10]: (i) direct transitions between the energy levels involving absorption and emission of surface-acoustic phonons, and (ii) the absorption due to relaxation processes [11]. The latter arise from the periodic motion of the energy levels under the influence of the external SAW field which, at finite temperatures $T > 0$, leads to a non-equilibrium occupation of the levels. Energy dissipation is then due to inelastic relaxation mechanisms, which attempt to restore instantaneous equilibrium occupancies among the energy levels. Such processes were first introduced by Debye in connection with the relaxation of a vibrating dipole in a liquid, and then extensively discussed in connection with energy dissipation in various physical systems. In the following, we call the relaxational absorption simply Debye absorption. The Debye processes involve the occupation relaxation rate of the electronic system which is related to the energy relaxation rate τ_ϵ . The direct transitions depend on the phase coherence time τ_ϕ . In terms of the density matrix formalism, τ_ϵ^{-1} and τ_ϕ^{-1} can be identified with the diagonal and the off-diagonal relaxation rates, respectively; see the discussion in ref. [12]. Indeed, the former describes the approach to equilibrium, while the latter is associated with the destruction of coherence effects, *i.e.*, the suppression of the off-diagonal elements of the density matrix.

To describe the energy spectrum of the dots at the scale $\epsilon < \Delta$, we use the Random Matrix Theory (RMT) [13]. According to RMT, the statistical properties of the spectrum depend only on the global symmetries of the system, such that three pure cases can be distinguished: systems with time reversal symmetry (orthogonal ensemble, $B = 0$), systems with broken time reversal symmetry (unitary ensemble, $B \neq 0$), and systems without rotational symmetry (symplectic ensemble, τ_{so} small and $B = 0$). The crossover between these ensembles depends on the energy scale of interest, which may allow to discriminate between different sound attenuation mechanisms, cf. below.

In the following, we give a brief derivation of the major results. We focus on the case

of diffusive dots [14], where the size of the dots exceeds the elastic mean free path, $L > \ell$, and the dimensionless conductance is large, $g \gg 1$. For $T < \Delta$, only a narrow pair of levels (say 1 and 2) with energetic separation $\epsilon_1 - \epsilon_2 = \epsilon < \Delta$ is of importance for the Debye processes because all other levels, up to exponentially small corrections, are completely filled or completely empty; thus a non-equilibrium occupation does not occur. The power absorbed due to these processes by a two-level system is [11]

$$Q_D(\epsilon) = \left(-\frac{\partial f(\epsilon)}{\partial \epsilon} \right) \frac{\omega^2 \tau_\epsilon(\epsilon)}{1 + \omega^2 \tau_\epsilon^2(\epsilon)} |M_{11} - M_{22}|^2. \quad (1)$$

The matrix elements M are calculated with the eigenfunctions of the states 1 and 2 and the piezoelectric field induced by the SAW. (The deformation-potential coupling is negligibly small.) The occupation probabilities of the levels 1 and 2 are given by $f(\epsilon) = [\exp(\epsilon/T) + 1]^{-1}$ and $f(-\epsilon)$, respectively. Equation (1) has to be averaged over different realizations of disorder in different dots, being associated with statistically independent [15] variations of the eigenfunctions 1 and 2 and the level spacing ϵ . We assume that one can average separately over the wave functions in τ_ϵ and in the difference of matrix elements. The latter quantity is calculated below [eq. (7)] and found to be independent of ϵ in the range of interest. The remaining averaging over ϵ uses the level correlation function $R(\epsilon)$ [13], that has the limits

$$R(\epsilon) = \frac{1}{\Delta} \begin{cases} c_\beta |\epsilon/\Delta|^\beta & \text{for } |\epsilon| \ll \Delta, \\ 1 & \text{for } |\epsilon| \gg \Delta, \end{cases} \quad (2)$$

where $c_\beta \simeq 1$, and, as usual, $\beta = 1, 2$, and 4 for the orthogonal, unitary, and symplectic ensembles, respectively. As a result (numerical factors of order unity are skipped),

$$Q_D = |M_{11} - M_{22}|^2 \frac{\omega^2 \tau_\epsilon(T)}{1 + \omega^2 \tau_\epsilon^2(T)} R(T), \quad (3)$$

where we have used that the characteristic energy scale in eq. (1) is given by $(-\partial f/\partial \epsilon)$ and, hence, is of order T . Indeed, the energy relaxation rate $\tau_\epsilon^{-1}(\epsilon) \propto \epsilon^p$ depends too weakly on ϵ in order to provide a cut-off on the average over ϵ . In particular, one can show [16] that inelastic transitions induced by the piezoelectric interaction with thermal phonons lead for $\epsilon < T$ to $\tau_\epsilon^{-1}(\epsilon) \propto \epsilon^2$, *i.e.*, $p = 2$, while electron-electron processes are expected to yield p in the range between 1 and 2; see *e.g.* ref. [17]. This is an important difference compared to the case of 3D metallic particles, where the deformation-potential coupling, associated with $p = 4$, is dominant (see ref. [6]), thus providing a cut-off depending on ω and τ_ϵ .

Let us now turn to the power absorbed due to direct transitions,

$$Q_{\text{dir}} = \omega^2 \sum_{m \neq n} \frac{\tau_\phi}{1 + \tau_\phi^2(\epsilon_{mn} - \omega)^2} \frac{f_n - f_m}{\epsilon_{mn}} |M_{mn}|^2, \quad (4)$$

where $\epsilon_{mn} = \epsilon_m - \epsilon_n$ and f_n measures the occupation probability of level n . Since Q_{dir} is determined by transitions close to the last occupied level (at $T = 0$), we neglect a possible dependence of τ_ϕ^{-1} on ϵ_{mn} and explicitly indicate in the following only its temperature dependence. Two main contributions to the sum in eq. (4) can be identified: the first is due to dots where at $T = 0$ the last occupied level is separated from the first empty one by a gap of order ω , while the second arises from dots with gaps of order Δ . In the latter case, transitions occur only due to the overlap of the tails of the broadened levels. This overlap is strongest for adjacent states, *i.e.*, $\epsilon_{mn} = \epsilon_{m,m\pm 1} \simeq \Delta$. Thus, the level correlation function drops out and we obtain

$$Q_t = |M_{12}|^2 (\omega/\Delta)^2 [\tau_\phi(T)\Delta]^{-1}, \quad (5)$$

where the off-diagonal matrix element M_{12} , that is independent of ϵ_{12} , is given in eq. (7) below. For dots with gaps as small as ω , the level broadening is not relevant and, hence, the Lorentzian in eq. (4) can be replaced by $\pi\delta(\epsilon_{mn} - \omega)$. The occupation probabilities of these narrow pairs of levels are again given by $f(\pm\epsilon)$, cf. eq. (1). This yields the resonant contribution (cf. the calculations in refs. [18] and [19])

$$Q_r = |M_{12}|^2 \omega \tanh(\omega/2T) R(\omega). \quad (6)$$

This result is valid for $\omega, T \ll \Delta$.

The matrix elements in eqs. (3), (5), and (6) are given by $M_{mn} = \langle m | V_\omega \exp(i\mathbf{q}\mathbf{r}) | n \rangle$, where $V_\omega = \gamma_q / (\mathcal{L}\varepsilon)$ represents the screened piezoelectric potential arising from the SAW. The interaction vertex γ_q was calculated in ref. [20], and $\mathcal{L}^2$ is the normalization area in the plane of the quantum dots. The screening of the SAW potential is described by the dielectric function ε that is very much dependent on the fact that we are studying a 2D system: First, the piezoelectric field penetrates the quantum dot completely and, hence, ε may be taken to be $\mathbf{r}$ -independent. The sound attenuation thus clearly probes the behaviour of the electron wavefunctions within the whole dot. In 3D metallic particles only the electrons in a distance up to the screening length from the surface are subject to an external field [6], since the field decreases exponentially towards the interior of the particle. Secondly, the Coulomb interaction between different dots (which is in leading approximation a dipole-dipole interaction decaying like r^{-3}) is not very effective for a 2D array of dots. Indeed, experiments have shown [21] that the interdot coupling leads even in dense arrays to a change of the local electric field of no more than 25%. This is again very different from the case of a 3D system containing metallic grains, where their mutual coupling has to be taken into account with care; cf. the discussion in ref. [19]. Neglecting the interdot coupling, the calculation of ε coincides in the linear screening regime with the evaluation of the density response function. Interestingly, while the SAW attenuation probes the properties of a few levels close to the last occupied level at $T = 0$, the density response function is determined by (virtual) transition processes with large energy transfers $|\epsilon_{mn}| \sim E_c = D/L^2 = g\Delta \gg \Delta$, where D is the diffusion coefficient of the electron gas. Consequently, the screening is neither sensitive to the symmetry of the system ($\beta = 1, 2, 4$) nor depends on the discreteness of the spectrum. It is therefore natural that the dielectric function reduces to its familiar expression for a diffusive system, taken in the limits $\omega \rightarrow 0$ and $q \sim L^{-1}$, *i.e.*, $\varepsilon \simeq L/a_B \gg 1$ [22], where a_B is the Bohr radius.

For typical sound frequencies, $qL \ll 1$, and, hence, the matrix element simplifies to $M_{mn} = iV_\omega \mathbf{q} \langle m | \mathbf{r} | n \rangle$. [For $m = n$ the first expansion term is canceled after taking the difference of diagonal matrix elements, cf. with eq. (3), *i.e.*, we have again to consider the matrix element of $\mathbf{r}$.] Disorder averaged products of these matrix elements can be calculated using, *e.g.*, quasi-classical methods [23, 19] or wavefunction correlators derived within the supersymmetry approach [24]. We obtain

$$|M_{11} - M_{22}|^2 \simeq |M_{12}|^2 \simeq (\gamma_q q a_B)^2 / (\mathcal{L}^2 g). \quad (7)$$

This result is valid for energy differences $|\epsilon_1 - \epsilon_2| \leq E_c$.

The SAW attenuation coefficient Γ is related to the energy loss Q according to $\Gamma = \mathcal{N} \mathcal{L}^2 Q / (\hbar \omega s)$, where $\mathcal{N}$ is the areal density of quantum dots and s the sound velocity. Collecting the above results for Q and the matrix elements yields

$$\Gamma_D = A \frac{\omega}{s} \frac{\omega \tau_\epsilon(T)}{1 + \omega^2 \tau_\epsilon^2(T)} \hbar \omega R(T), \quad (8)$$

$$\Gamma_t = A \frac{\omega}{s} \left(\frac{\hbar \omega}{\Delta} \right)^3 \frac{1}{\omega \tau_\phi(T)}, \quad (9)$$

$$\Gamma_{\text{r}} = A \frac{\omega}{s} \tanh\left(\frac{\hbar\omega}{2T}\right) \hbar\omega R(\hbar\omega), \quad (10)$$

for the Debye attenuation, the attenuation due to the tails of the broadened levels, and the resonant attenuation, respectively, and $A = (\mathcal{N}/g)(a_B\gamma_q/\hbar s)^2$. Let us now substitute some realistic parameters in order to estimate the relative magnitude of these terms. In GaAs/Al_xGa_{1-x}As heterostructures, $\gamma_q/s \approx 1$ [20]. For the parameters $L = 300$ nm and $\Delta = 1$ K introduced above, a value of $g \sim 5$ results in $D \sim 10^{-2}$ m²s⁻¹. We put $T \sim 0.1$ K, and assume $\tau_\phi^{-1}(T) \sim 10^9$ s⁻¹ and $\tau_\epsilon^{-1}(T) \sim 10^8$ s⁻¹. The phase breaking rate is about one order of magnitude smaller than the one recently derived from *transport* experiments [7, 8] with ballistic quantum dots of size $L \sim 2$ μ m. This reduction of the dephasing seems to be reasonable since we are considering isolated dots without leads. The energy relaxation rate is only sensitive to inelastic scattering events with a substantial energy transfer and, hence, should be always smaller than τ_ϕ^{-1} [25]. Then, for typical SAW frequencies, we find the inequalities $\Delta > T > \tau_\phi^{-1} \geq \omega \geq \tau_\epsilon^{-1}$, where $T > \omega$ is most probably always fulfilled. Based on these parameters we obtain $\Gamma_{\text{D}} \gg \Gamma_{\text{r}} \geq \Gamma_{\text{t}}$ for $\beta = 1$, and $\Gamma_{\text{D}} \gg \Gamma_{\text{t}} \gg \Gamma_{\text{r}}$ for $\beta = 2$. The Debye absorption remains dominant if $\omega\tau_\epsilon(T)$ varies in the range $10^{-3} - 10^2$. Thus, the measurement of $\Gamma(T) = \Gamma_{\text{D}}(T)$ [eq. (8)] at a fixed SAW frequency accesses the temperature dependence of the energy relaxation time $\tau_\epsilon(T)$ in systems with or without time reversal symmetry. Very interesting is the case of broken rotational symmetry, $\beta = 4$, because Γ_{D} may now decrease below $\Gamma_{\text{t}} [\gg \Gamma_{\text{r}}]$, permitting the measurement of both $\tau_\epsilon(T)$ and $\tau_\phi(T)$ at different frequencies. Generally, Γ_{D} is [depending on the density of the dot lattice and other parameters] about 2-3 orders of magnitude smaller than the maximum SAW attenuation due to an extended 2DEG, which should be within the experimental resolution.

This discussion has shown that the global symmetries of the system (described by the parameter β) determine directly which of the various contributions to the attenuation coefficient [eqs. (8)–(10)] is dominant. The parameter β enters via the level correlation function $R(\epsilon)$, eq. (2), if energy scales smaller than Δ are relevant. This is not the case for the tail absorption so that Γ_{t} is essentially independent of the symmetries. The crossover from the time reversal invariant case ($\beta = 1$) to that with broken time reversal symmetry ($\beta = 2$) is achieved by applying a magnetic field $B \gg B^*$. The very small threshold field is given by $B^* \simeq (\Phi_0/L^2)\sqrt{\epsilon^*/E_c}$, where Φ_0 is the flux quantum and ϵ^* is the typical energy scale of the transitions. Since Γ_{D} and Γ_{r} are associated with $\epsilon^* = T$ and $\epsilon^* = \omega$, respectively, the threshold fields are different,

$$B_{\text{D}}^*/B_{\text{r}}^* = \sqrt{T/\omega}. \quad (11)$$

Similarly, the rotational symmetry can be broken by increasing the spin-orbit scattering rate τ_{so}^{-1} above ϵ^* . One should note that the variation of β results in a significant change of the magnitude of Γ . In this sense, the dependence of the sound absorption on weak magnetic fields and spin-orbit scattering is much more pronounced in the discrete spectrum limit than in the quasicontinuous case. In the latter, this dependence arises solely from weak localization *corrections* to the conductance g (entering A) [22]. In the present case, these corrections can safely be ignored as compared to the effects associated with $R(\epsilon)$.

In summary, we have considered the attenuation of surface-acoustic waves due to an array of quantum dots in the discrete spectrum limit, arising from both direct and Debye processes. It has been shown that non-invasive measurements of Γ can yield the temperature dependence of both the energy and the phase breaking rate of an isolated electronic system. The sensitivity to weak magnetic fields or the spin-orbit scattering (“weak localization effects”) is greatly enhanced as compared to the case of a continuous spectrum. It might be possible to observe the transition from the thermal-phonon to the electron-electron dephasing, which is known to

occur at around 1 K [9]. We hope that these calculations will stimulate further experimental investigations in this field.

Financial support by the German-Israeli Foundation, the Fund for Basic Research administered by the Israel Academy of Sciences and Humanities, and the Deutsche Forschungsgemeinschaft (A. K.) is gratefully acknowledged. We thank Y. Gefen, Y. Imry, and A. Wixforth for valuable discussions.

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